Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

Rohm Semiconductor 2SA1807TLP

For any questions, you can email us directly: sales@integrated-circuit.com

Distributor of Rohm Semiconductor: Excellent Integrated System Limited

Datasheet of 2SA1807TLP - TRANS PNP 600V 1A TO252

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

Transistors 2SA1807
2SA1862

High-voltage Switching Transistor (Telephone, Power supply) (—600V, —1A)

2SA1807

Features

- 1) High breakdown voltage. (BVcEo=-600V)
- 2) Low saturation voltage, typically $V_{CE(sat)} = -0.25V$ at Ic / IB=-300mA / -60mA.
- 3) High switching speed, typically tf=0.4 μ s at Ic=-500mA
- 4) Wide SOA (safe operating area).

Packaging specifications and hre

Type	2SA1807
Package	CPT3
hfe	NP
Code	TL
Basic ordering unit (pieces)	2500

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-600	V
Collector-emitter voltage	VCEO	-600	V
Emitter-base voltage	VEBO	— 7	V
Collector current	lc ·	-1	A (DC)
		-2	A (Pulse) *
Collector power dissipation	Pc	1	W
	Pc	10	W (Tc=25°C)
Junction temperature	Tj	150	ొ
Storage temperature	Tstg	-55~+150	°C

^{*} Single pulse, Pw=100ms

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-600	_	_	V	Ic=-50 μ A
Collector-emitter breakdown voltage	BVceo	-600	_	_	V	Ic=-1mA
Emitter-base breakdown voltage	ВУЕВО	-7	_	_	V	I _E =-50 μ A
Collector cutoff current	Ісво	_	_	-10	μΑ	V _{CB} =-600V
Emitter cutoff current	Ієво	_	_	-10	μΑ	V _{EB} =-7V
Collector-emitter saturation voltage	VCE(sat)	_	-0.25	-1	V	Ic/Is=-300mA/-60mA
Base-emitter saturation voltage	VCE(sat)	_	_	-1.2	V	Ic/IB=-300mA/-60mA
DC current transfer ratio	hfe	56	_	180	_	VcE=-5V , Ic=-100mA
Transition frequency	f⊤	_	15	_	MHz	VcB=-10V , IE=50mA , f=5MHz
Output capacitance	Cob	_	40	_	pF	VcE=-10V, IE=0A, f=1MHz
Turn-on time	ton	_	0.2	_	μs	Ic=-500mA , RL=500 Ω
Storage time	tstg	_	1.8	_	μS	I _{B1} =-I _{B2} =-100mA
Fall time	tr	_	0.4	_	μs	Vcc <u>~</u> −250V

(96-102-A331)

High-voltage Switching Transistor (Telephone, Power supply) (-400V, -2A)

2SA1862

Features

- 1) High breakdown voltage. (BVcEo=-400V)
- 2) Low saturation voltage, typically $V_{CE(sat)} = -0.3V$ at $I_C / I_B = -500 \text{mA} / -100 \text{mA}$.
- 3) High switching speed, typically tf=0.4 μ s at Ic=-1A.
- 4) Wide SOA (safe operating area).

● Packaging specifications and hre

CPT3
Р
TL
2500

●Absolute maximum ratings (Ta=25℃)

	,			
Parameter	Symbol	Limits	Unit	
Collector-base voltage	Vcво	-400	V	
Collector-emitter voltage	Vceo	-400	V	
Emitter-base voltage	VEBO	— 7	V	
Collector current	1-	-2	A (DC)	
	lc lc	-4	A (Pulse) *	
Collector power dissipation	Pc	1	W	
	PC	10	W (Tc=25℃)	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55~+150	°C	

^{*} Single pulse, Pw=10ms

● Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	-400	_	_	V	Ic=-50 μ A
Collector-emitter breakdown voltage	BVceo	-400	_	_	V	Ic=-1mA
Emitter-base breakdown voltage	BVEBO	-7	_	_	V	IE=-50 μ A
Collector cutoff current	Ісво	_		-10	μΑ	V _{CB} =-400V
Emitter cutoff current	Ієво	_	_	-10	μА	V _{EB} =-5V
Collector-emitter saturation voltage	VCE(sat)	_	-0.3	-0.5	V	Ic/Is=-0.5A/-0.1A
Base-emitter saturation voltage	VCE(sat)	_	_	-1.2	V	Ic/IB=-0.5A/-0.1A
DC current transfer ratio	hre	82	_	180	_	VcE=-5V, Ic=-0.1A
Transition frequency	f⊤	_	18	_	MHz	V _{CB} =-10V , I _E =0.1A , f=5MHz
Output capacitance	Cob	_	30	_	pF	Vc=-10V, I=0A, f=1MHz
Turn-on time	ton	_	0.2	_	μs	Ic=-1A, RL=150Ω
Storage time	tstg	_	1.8	_	μs	I _{B1} =-I _{B2} =-0.2A
Fall time	t f	_	0.4	_	μ\$	Vcc <u>~</u> 150V

(96-109-A343)



Distributor of Rohm Semiconductor: Excellent Integrated System Limited

Datasheet of 2SA1807TLP - TRANS PNP 600V 1A TO252

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

Appendix

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any
 means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
 use and operation. Please pay careful attention to the peripheral conditions when designing circuits
 and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
 otherwise dispose of the same, no express or implied right or license to practice or commercially
 exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document use silicon as a basic material.
 Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

